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TSHF6210

RoHS

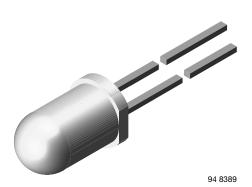
HALOGEN

FREE

GREEN

Vishay Semiconductors

High Speed Infrared Emitting Diode, 890 nm, Surface Emitter Technology



DESCRIPTION

TSHF6210 is an infrared, 890 nm emitting diode based on surface emitter chip technology with high radiant power and high speed, molded in a clear, untinted plastic package.

FEATURES

Package type: leadedPackage form: T-1¾

• Dimensions (in mm): Ø 5

• Peak wavelength: $\lambda_p = 890 \text{ nm}$

High reliability

• High radiant power

· High radiant intensity

• Angle of half intensity: $\varphi = \pm 8^{\circ}$

Low forward voltage

· Suitable for high pulse current operation

Good spectral matching with Si photodetectors

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



- Infrared high speed remote control and free air data transmission systems with high modulation frequencies or high data transmission rate requirements
- Transmission systems according to IrDA requirements and for carrier frequency based systems (e.g. ASK/FSK coded, 450 kHz or 1.3 MHz)

| PRODUCT SUMMARY | | | | | |
|-----------------|------------------------|--------------|---------------------|---------------------|--|
| COMPONENT | I _e (mW/sr) | φ (°) | λ _P (nm) | t _r (ns) | |
| TSHF6210 | 327 | ± 8 | 890 | 10 | |

Note

• Test conditions see table "Basic Characteristics"

| ORDERING INFORMATION | | | | | |
|----------------------|-----------|------------------------------|--------------|--|--|
| ORDERING CODE | PACKAGING | REMARKS | PACKAGE FORM | | |
| TSHF6210 | Bulk | MOQ: 4000 pcs, 4000 pcs/bulk | T-1¾ | | |

Note

MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) | | | | | |
|--|---------------------------------------|-------------------|-------------|------|--|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT | |
| Reverse voltage | | V_{R} | 5 | V | |
| Forward current | | I _F | 100 | mA | |
| Peak forward current | $t_p/T = 0.5, t_p = 100 \mu s$ | I _{FM} | 200 | mA | |
| Surge forward current | t _p = 100 μs | I _{FSM} | 1 | А | |
| Power dissipation | | P_V | 170 | mW | |
| Junction temperature | | Tj | 100 | °C | |
| Ambient temperature range | | T _{amb} | -40 to +85 | °C | |
| Storage temperature range | | T _{stg} | -40 to +100 | °C | |
| Soldering temperature | t ≤ 5 s, 2 mm from case | T _{sd} | 260 | °C | |
| Thermal resistance junction to ambient | J-STD-051, leads 7 mm soldered on PCB | R _{thJA} | 230 | K/W | |





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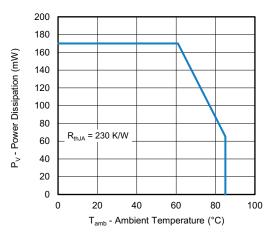


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

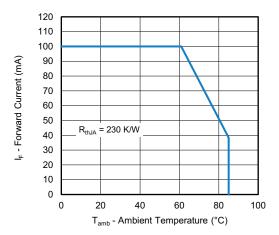


Fig. 2 - Forward Current Limit vs. Ambient Temperature

| BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | |
|---|---|------------------|------------------------------------|------|------|-------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Forward voltage | $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$ | V_{F} | - | 1.5 | 1.7 | V |
| | $I_F = 1 \text{ A}, t_p = 100 \mu s$ | V_{F} | - | 3 | - | V |
| Temperature coefficient of V _F | $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$ | TK_{VF} | - | -1.3 | - | mV/K |
| Reverse current | | I _R | Not designed for reverse operation | | | μA |
| Junction capacitance | $V_R = 0 \text{ V, f} = 1 \text{ MHz, E} = 0 \text{ mW/cm}^2$ | Cj | - | 55 | - | pF |
| Radiant intensity | $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$ | l _e | 150 | 327 | 450 | mW/sr |
| | $I_F = 1 \text{ A}, t_p = 100 \mu s$ | l _e | - | 2700 | - | mW/sr |
| Radiant power | $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$ | фe | - | 53 | - | mW |
| Temperature coefficient of ϕ_e | I _F = 100 mA | TKφe | - | -0.3 | - | %/K |
| Angle of half intensity | | φ | - | ± 8 | - | 0 |
| Peak wavelength | I _F = 100 mA | λ_{p} | - | 890 | - | nm |
| Spectral bandwidth | I _F = 100 mA | Δλ | - | 40 | - | nm |
| Temperature coefficient of λ_p | I _F = 100 mA | TKλ _p | - | 0.3 | - | nm/K |
| Rise time | I _F = 100 mA | t _r | - | 10 | - | ns |
| Fall time | I _F = 100 mA | t _f | - | 10 | - | ns |

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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

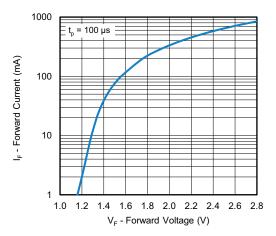
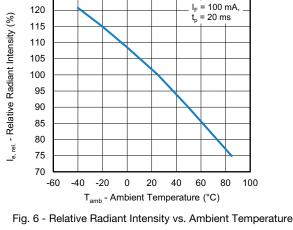


Fig. 3 - Forward Current vs. Forward Voltage



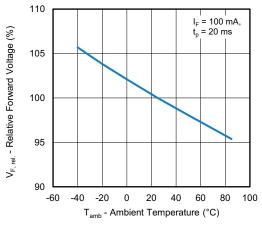


Fig. 4 - Relative Forward Voltage vs Ambient Temperature

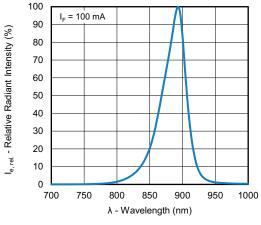


Fig. 7 - Relative Radiant Intensity vs. Wavelength

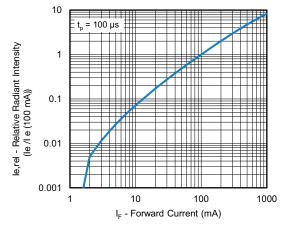


Fig. 5 - Relative Radiant Intensity vs. Forward Current

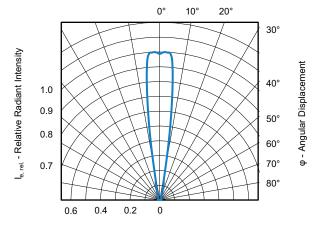


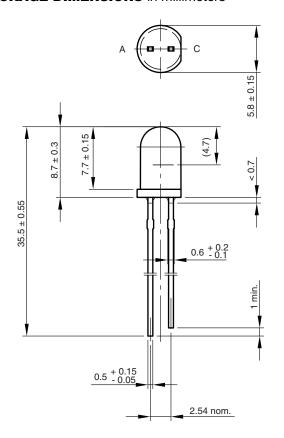
Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

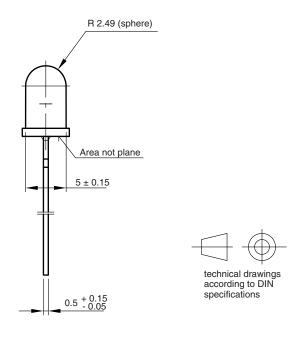


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PACKAGE DIMENSIONS in millimeters





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